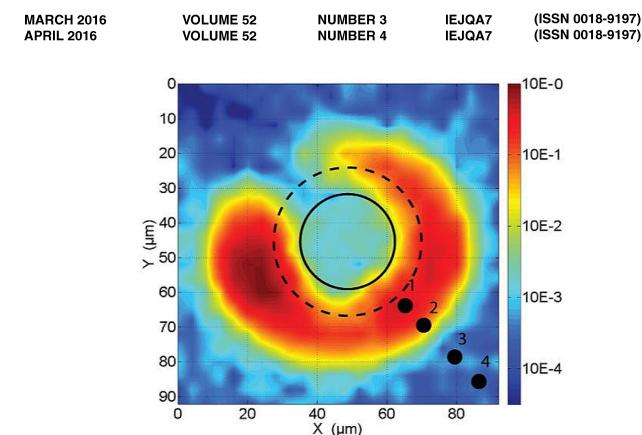
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A PUBLICATION OF THE IEEE PHOTONICS SOCIETY



This Print Collection Contains the Following Issues:



Normalized maps of spurious counts when scanning the SPAD active area and its periphery with a pulsed laser stimulus before the gate with $\Delta t=10$ ns (top) and $\Delta t=100$ ns (bottom), respectively. The active area is delimited by a solid line and the edge of the shallow diffusion by the dashed line. The anode metal stripe shields the laser illumination in the top left corner of the figure. Points 1 to 4 are the four spot positions mentioned in legend of Fig. 12 and where the curves therein reported are acquired. Operating conditions: $V_{\rm EX}=5$ V, $V_{\rm UV}=0.5$ V, $T_{\rm ON}=20$ ns, $T_{\rm OFF}=100~\mu{\rm s}$, Temperature = 225 K (Calandri *et al.*, Article #4500107).

For the March 2016 issue, see Article #0100301 for the Table of Contents. For the April 2016 issue, see Article #0100401 for the Table of Contents.



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